# Silicon Carbide Schottky Diode

650 V, 8 A

# FFSB0865B

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### **Features**

- Max Junction Temperature 175°C
- Avalanche Rated 33 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Applications**

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

## **MAXIMUM RATINGS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage	$V_{RRM}$	650	V	
Single Pulse Avalanche Energy ( $I_{L(pk)} = 11.5 \text{ A}, L = 0.5 \text{ mH}, V = 50$	E <sub>AS</sub>	33	mJ	
Continuous Rectified Forward @ T <sub>C</sub> < 147		lF	8.0	Α
Current	@ T <sub>C</sub> < 135		10.1	
Non–Repetitive Peak Forward $T_C = 25^{\circ}C$ Surge Current $t_P = 10 \mu s$		I <sub>FM</sub>	577	Α
	$T_{C} = 150^{\circ}C$ $t_{P} = 10 \ \mu s$		533	
Non-Repetitive Forward Surge Current (Half-Sine Pulse)	$T_C = 25$ °C $t_P = 8.3$ ms	I <sub>FSM</sub>	56	Α
Power Dissipation	T <sub>C</sub> = 25°C	P <sub>tot</sub>	73	W
	T <sub>C</sub> = 150°C		12	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C

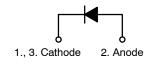
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



#### ON Semiconductor®

www.onsemi.com

V <sub>RRM</sub>	l <sub>F</sub>
650 V	8.0 A

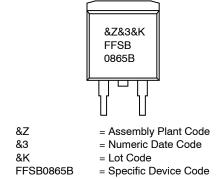


**Schottky Diode** 



TO-263 CASE 418BK

#### **MARKING DIAGRAM**



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

#### FFSB0865B

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case, Max.	$R_{\theta JC}$	2.05	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
ON CHARACTERISTICS			•	•		
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 8.0 A, T <sub>J</sub> = 25°C		1.39	1.7	V
		$I_F = 8.0 \text{ A}, T_J = 125^{\circ}\text{C}$		1.55	2.0	1
		I <sub>F</sub> = 8.0 A, T <sub>J</sub> = 175°C		1.71	2.4	1
Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 650 V, T <sub>J</sub> = 25°C		0.5	40	μΑ
		V <sub>R</sub> = 650 V, T <sub>J</sub> = 125°C		1.0	80	1
		V <sub>R</sub> = 650 V, T <sub>J</sub> = 175°C		2.0	160	1
CHARGES, CAPACITANCES & G	SATE RESISTANCE					
Total Capacitive Charge	Q <sub>C</sub>	V <sub>C</sub> = 400 V		22		nC
	C <sub>tot</sub>	V <sub>R</sub> = 1 V, f = 100 kHz		336		pF
		V <sub>R</sub> = 200 V, f = 100 kHz		39		1
		V <sub>R</sub> = 400 V, f = 100 kHz		30		1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSB0865B	FFSB0865B	D <sup>2</sup> PAK	Tape & Reel <sup>†</sup>	330 mm	24 mm	800 Units

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <a href="https://example.com/BRD8011/D">BRD8011/D</a>.

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## **TYPICAL CHARACTERISTICS**

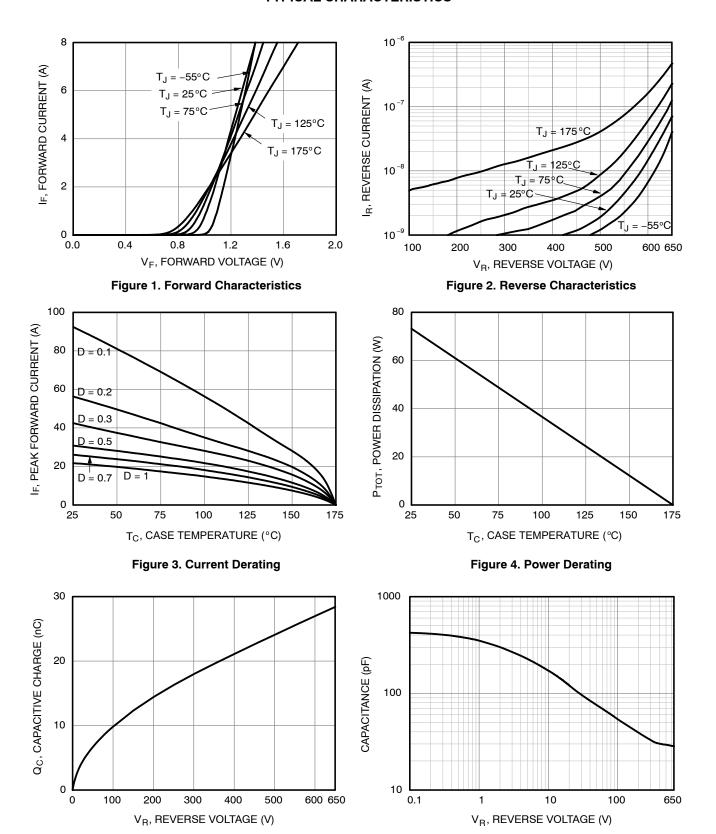


Figure 5. Capacitive Charge vs. Reverse Voltage

Figure 6. Capacitance vs. Reverse Voltage

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#### **TYPICAL CHARACTERISTICS**

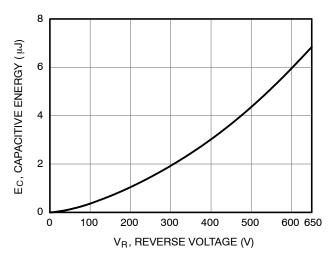


Figure 7. Capacitance Stored Energy

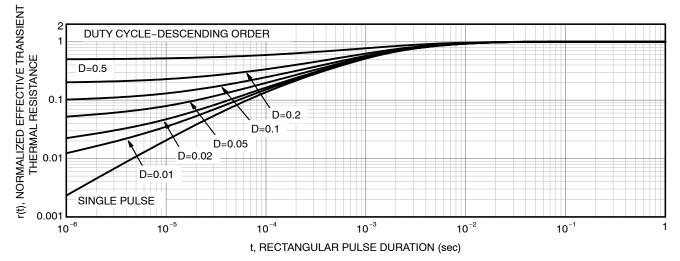
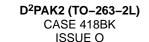
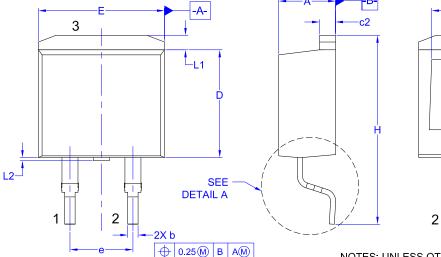
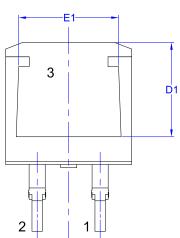


Figure 8. Junction-to-Case Transient Thermal Response



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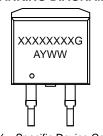


NOTES: UNLESS OTHERWISE SPECIFIED

- A) ALL DIMENSIONS ARE IN MILLIMETERS.
  B) REFERENCE JEDEC, TO-263, VARIATION AB.
- C) DIMENSIONING AND TOLERANCING PER
  DIMENSIONING AND TOLERANCING PER
- ASME Y14.5 2009.
  D) LANDPATTERN RECOMMENDATION PER IPC
- D) LANDPATTERN RECOMMENDATION PER IPO TO254P1524X482-3N

DETAIL A, ROTATED 90°	B)
SCALE: 2X	'(
GAUGE PLANE	D)
M	L3
B 0.10 SEATING —	-A1
GENERIC PLANE	—10.67—— <del>-</del>

GENERIC
MARKING DIAGRAM*



XXX = Specific Device Code

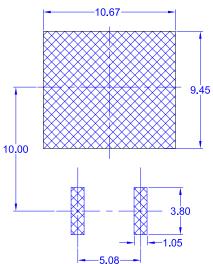
A = Assembly Location

Y = Year

WW = Work Week

G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.



LAND PATTERN RECOMMENDATION
UNLESS NOTED. ALL DIMS TYPICAL

MIN	NOM	MAX
4.06	4.57	4.83
0.00	0.10	0.25
0.51	0.81	0.99
0.30	0.407	0.74
1.14	1.30	1.65
8.38	8.69	9.65
7.30	7.80	8.30
9.65	10.16	10.67
8.00	8.00 8.62 9.0	
5.08 BSC		
14.60	15.35	15.88
1.78	2.54	2.79
0.90	1.29	1.68
0.00	0.15	0.25
0.25 BSC		
0° 4° 8°		8°
	4.06 0.00 0.51 0.30 1.14 8.38 7.30 9.65 8.00 14.60 1.78 0.90 0.00	4.06     4.57       0.00     0.10       0.51     0.81       0.30     0.407       1.14     1.30       8.38     8.69       7.30     7.80       9.65     10.16       8.00     8.62       5.08 BS       14.60     15.35       1.78     2.54       0.90     1.29       0.00     0.15       0.25 BS

**MILLIMETERS** 

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